

Artificial diamonds as particle detectors and radiation dosimeters

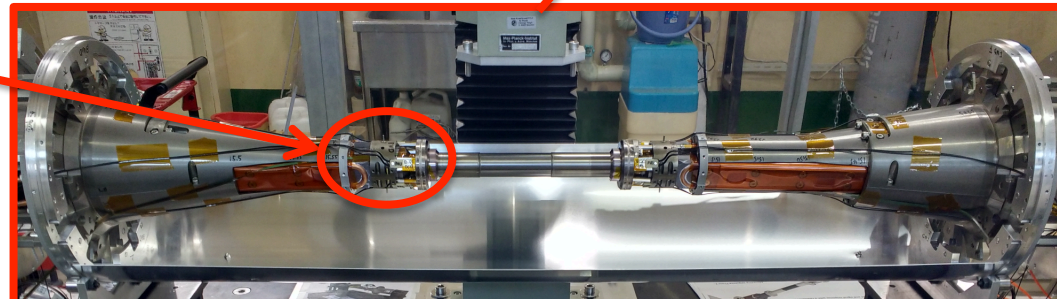
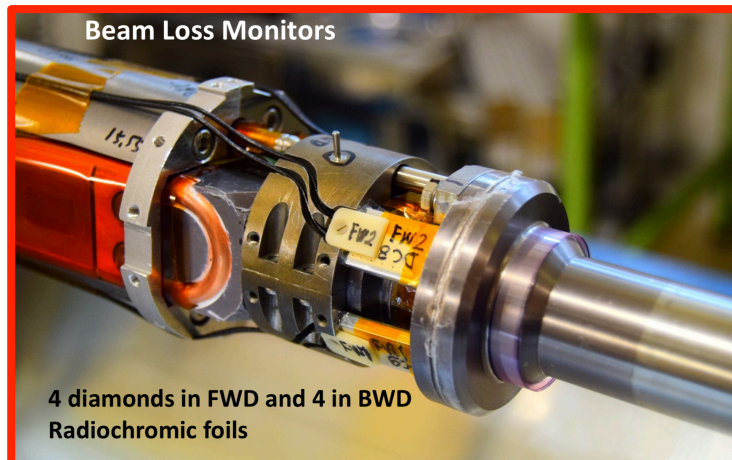
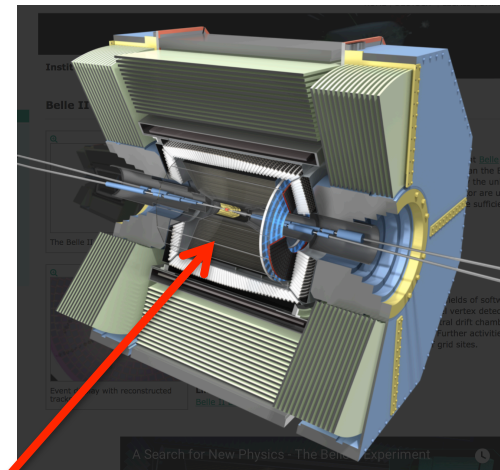
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JENNIFER Summer School, Trieste 02/07/2018

- Diamond sensors in HEP
- Detection of charged particles by ionization
- Diamonds as “solid-state ionization chambers”
- Characterization of diamond sensors with α -particles
- Experimental set-up and data collection
- Data analysis challenge

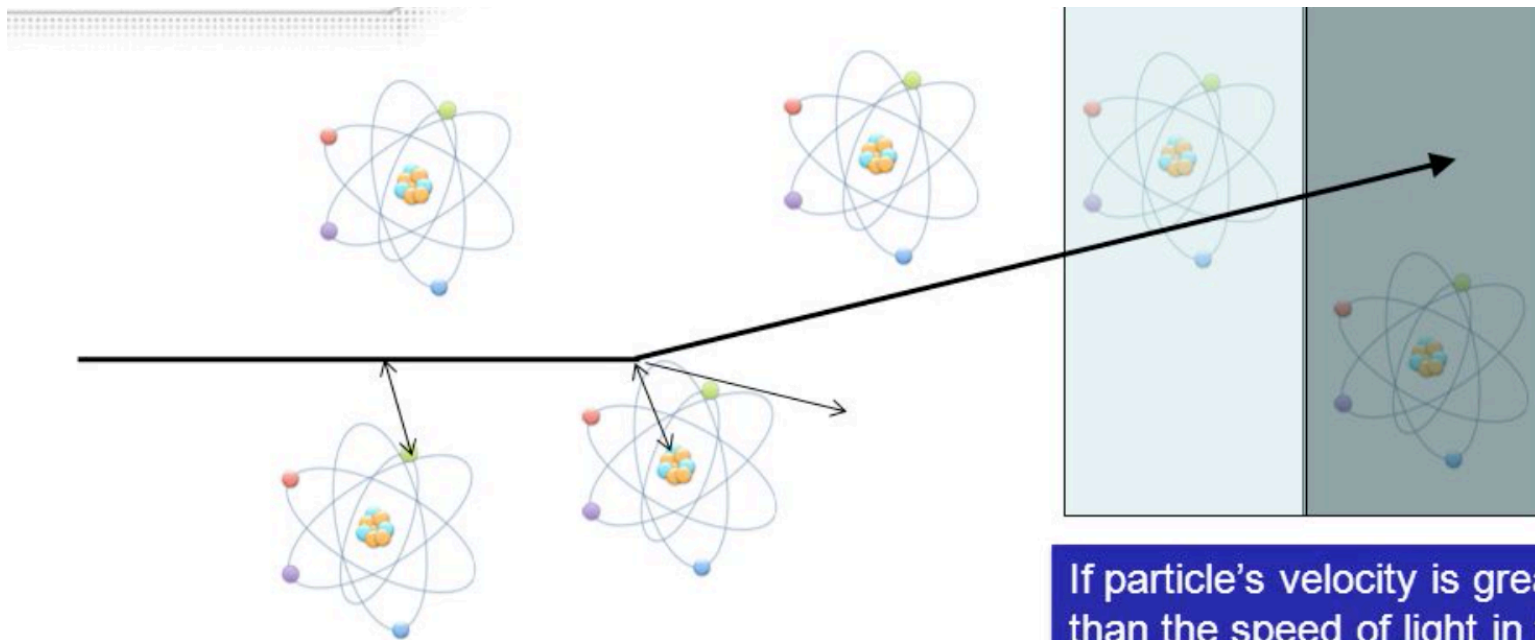
Diamonds in HEP: active research

- RD42 Collaboration & High Luminosity LHC at CERN
 - ATLAS Diamond Beam Monitor (DBM)
 - CMS Pixel Luminosity Telescope (PLT)
- Belle II experiment at the SuperKEKB collider (Japan)
 - Belle II Radiation Monitor and Beam Abort system
 - SuperKEKB bunch-by-bunch Luminosity Monitor



Particle detection by ionization

Energetic particles are *mainly* (not only!) detected by their energy lost in matter by ionization, directly (charged particles) or indirectly (neutral particles)



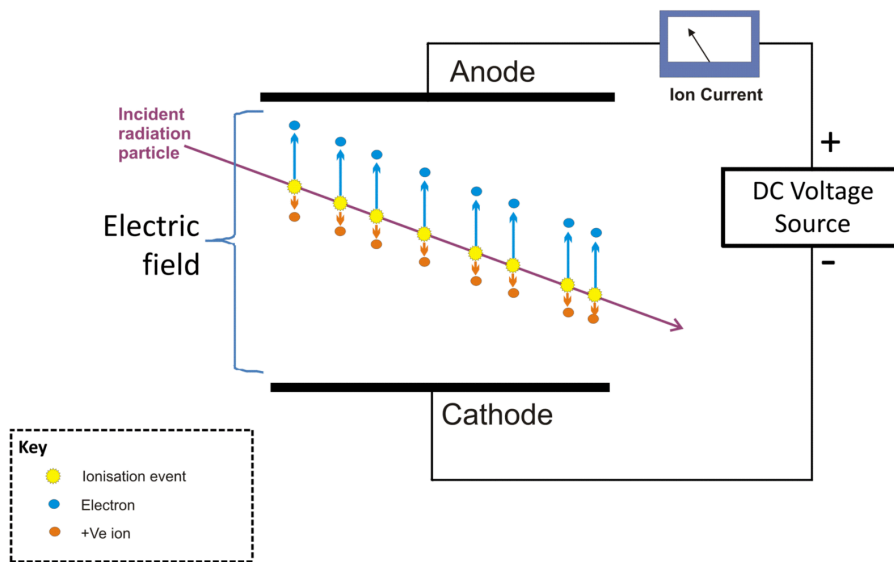
Interaction with atomic **electrons**. Particle loses energy; atoms are **excited** or **ionized**.

Interaction with atomic **nucleus**. Particle undergoes **multiple scattering**. Could emit a **bremstrahlung** photon.

If particle's velocity is greater than the speed of light in the medium \rightarrow **Cherenkov Radiation**. When crossing the boundary between median, $\sim 1\%$ probability of producing a **Transition Radiation X-ray**.

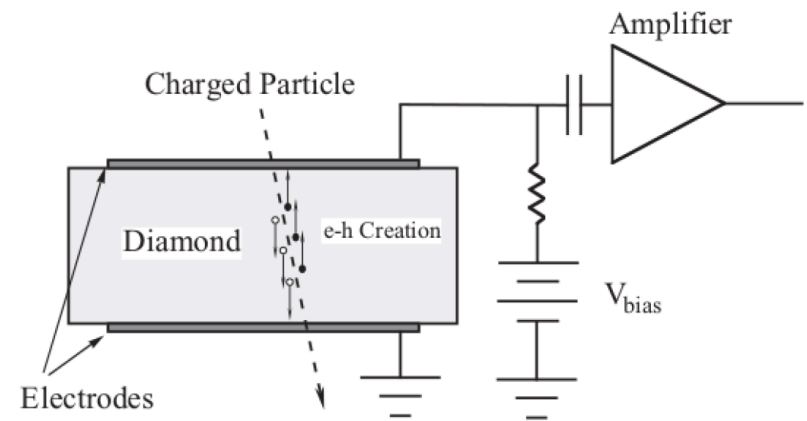
Diamonds: solid state ionization chambers

Parallel-plate ion chamber
filled with gas



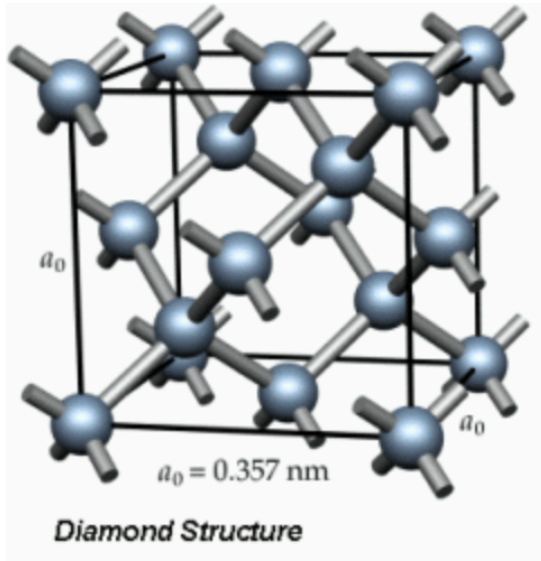
electrons and ions drift towards opposite electrodes, and diffuse (electrons 1000 times faster than ions)

Artificial diamond,
single- or poly-crystal,
with deposited metal electrodes

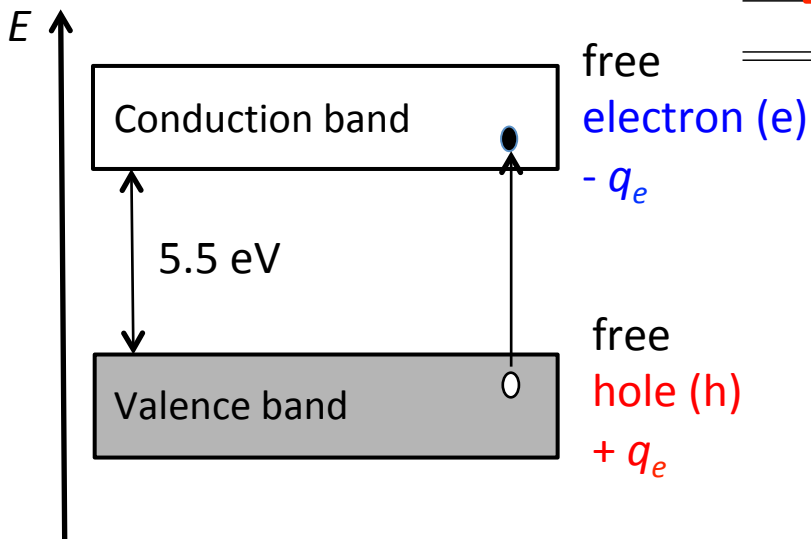


electrons and holes drift towards opposite electrodes, and diffuse (electrons and holes, similar speed)

Diamond: a “wide-gap semiconductor”



Property	Diamond	Silicon
Atomic number Z	6	12
Number of atoms N [10^{22} cm^{-3}]	17.7	5.0
Mass density ρ [g cm^{-3}]	3.53	2.33
Band gap E_g [eV]	5.47	1.12
Resistivity ρ_c [$\Omega \text{ cm}$]	$> 10^{12}$	2.3×10^5
Electron mobility μ_e [$\text{cm}^2 \text{ V}^{-1} \text{ s}^{-1}$]	1800	1350
Hole mobility μ_h [$\text{cm}^2 \text{ V}^{-1} \text{ s}^{-1}$]	1200	480
Electron saturation velocity v_e^s [10^6 cm s^{-1}]	26	10
Hole saturation velocity v_h^s [10^6 cm s^{-1}]	16	7
Thermal conductivity k [$\text{W cm}^{-1} \text{ K}^{-1}$]	21.9	1.5
Energy to create e-h pair E_{eh} [eV]	13	3.6
Displacement energy E_d [eV/atom]	42	15

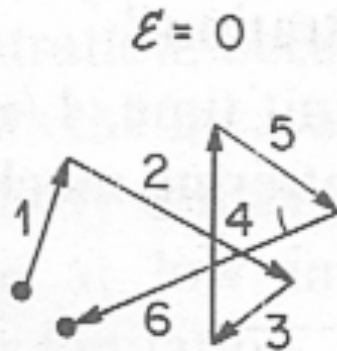


Forbidden band gap:
 $\approx 5.5 \text{ eV}$

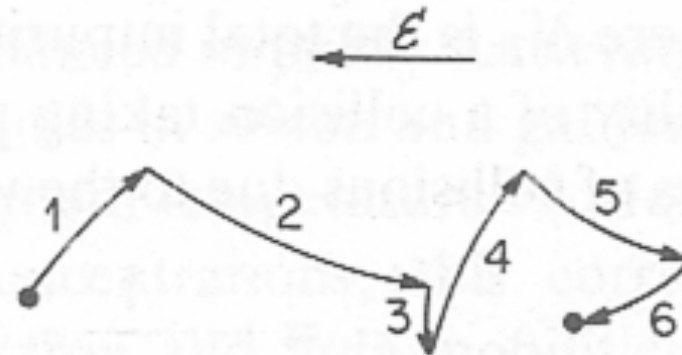
Average energy to create an e-h pair:
 $\approx 13 \text{ eV}$

Applied E-field: drift of electrons, holes

Example: electrons without/with an externally applied electric field



Random thermal motion:
diffusion only



Superimposed average drift velocity
due to E-field (similar for holes)

$$v_{e,x} = -\mu_e E_x$$
$$v_{h,x} = \mu_h E_x$$

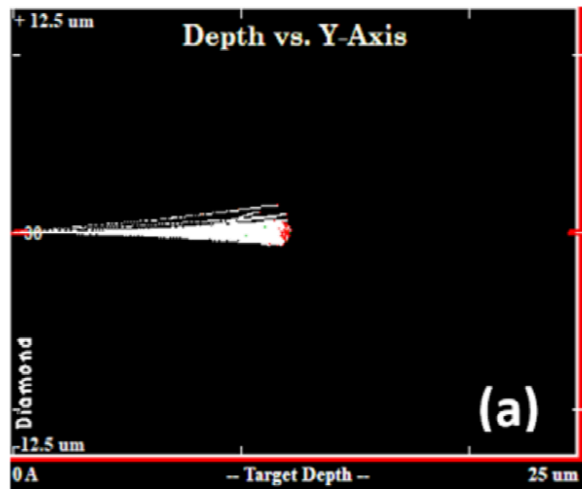
μ_e, μ_h : mobility

NB: *not so simple...*

Free electrons and holes may be captured by “traps” => space charge, distorted E_x

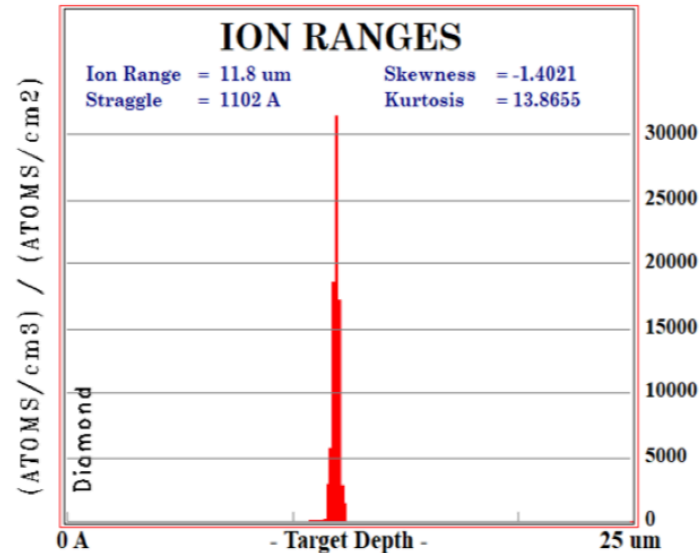
Charge carriers may be injected at the metallic electrode – diamond interface

α -particles to test diamond sensors



12 μm

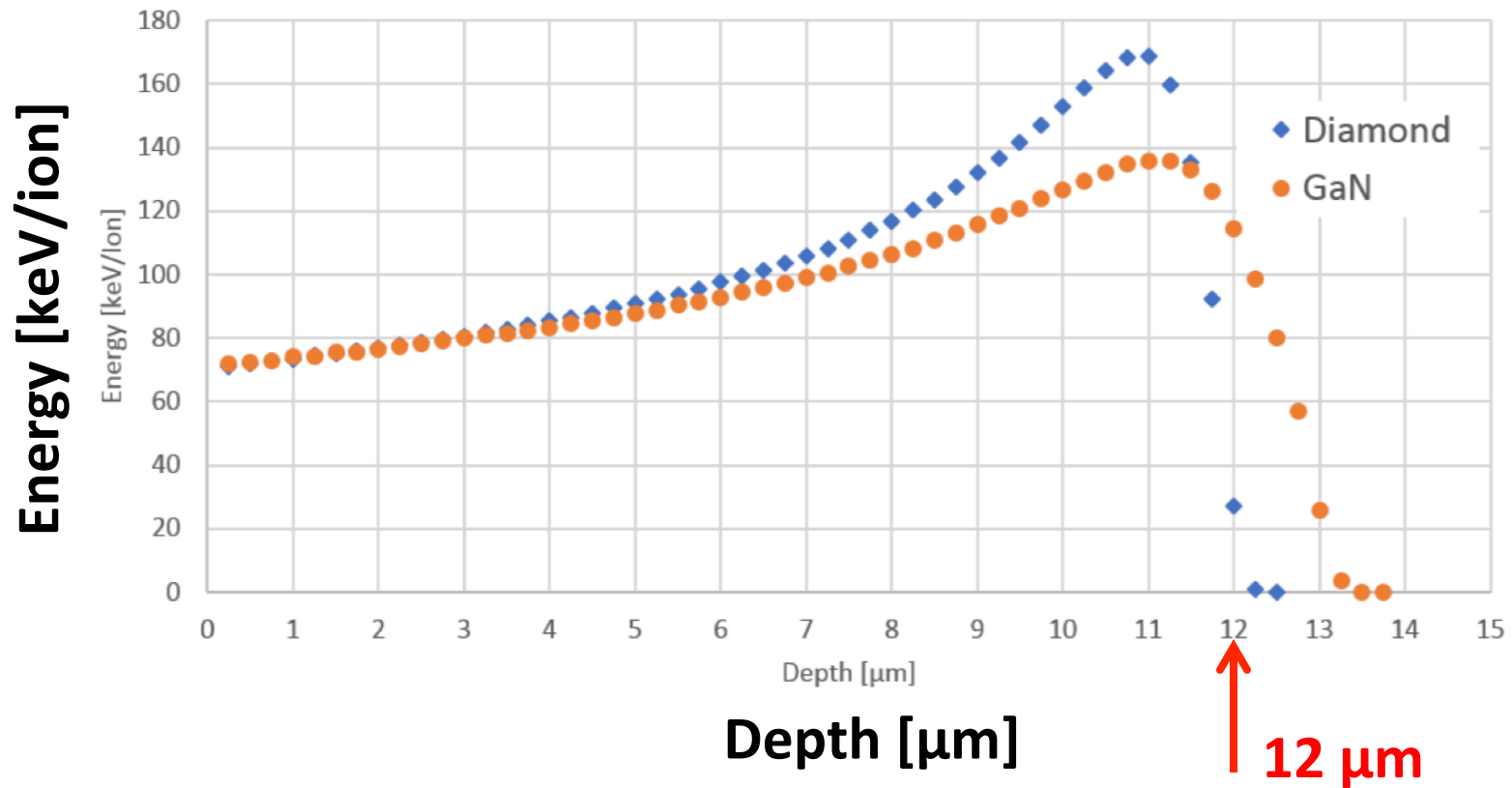
Energy [keV/ion]



12 μm

Simulation of 5.5 MeV α -particles from ^{241}Am radioactive source:
their *range* (penetration depth) is $\approx 11 \div 12 \mu\text{m}$ in diamond

Energy deposit of α -particles in diamond



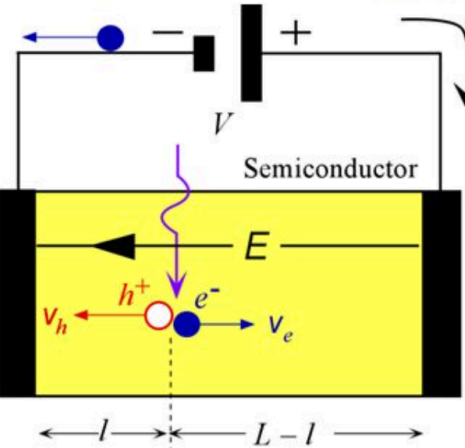
5.5 MeV α -particles
from ^{241}Am source

5.5 MeV lost within 11-12 μm
=> small cloud of e - h pairs
close to the entrance surface

Current induced by the motion of charges

Moving **electrons** induce a current pulse in the external circuit
(*sign changes for holes*)

Shockley-Ramo Theorem



External photocurrent due to the motion of this photogenerated electron is $i_e(t)$.
The electron is acted on by the force eE of the electric field.
When it moves a distance dx , work must be done by the external circuit. In time dt , the electron drifts a distance dx and does an amount of work $eEdx$

Work done $eEdx$ is provided by the battery in time dt
Electrical energy provided by the battery in time $dt = Vi_e(t)dt$
Thus, $eEdx = Vi_e(t)dt$. In time dt , the electron drift a distance $dx = v_e dt$

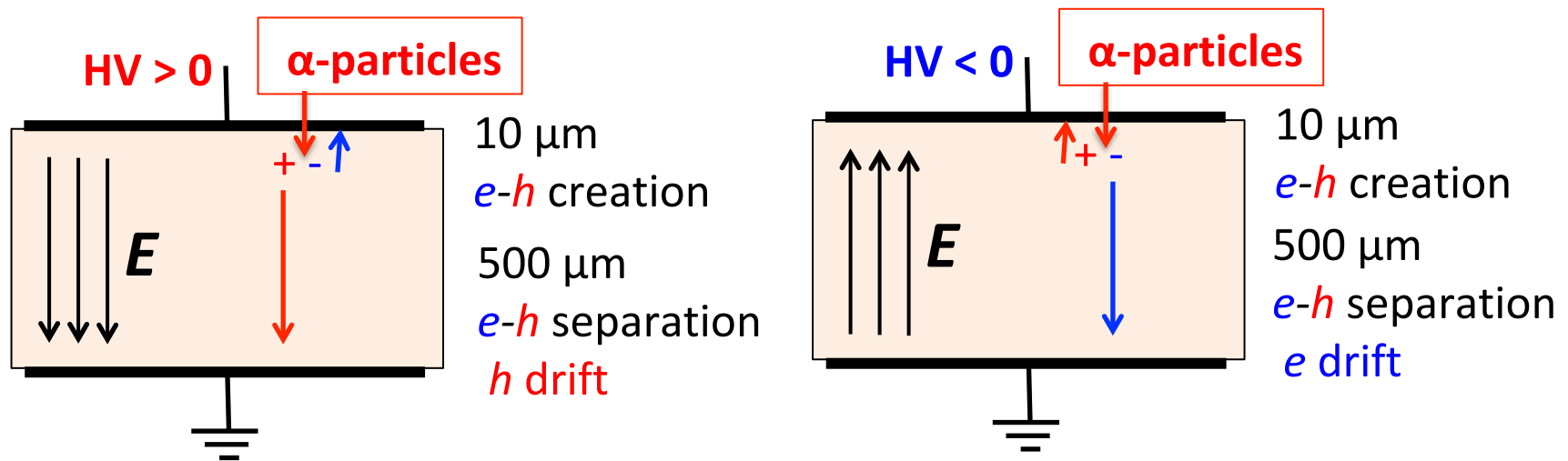
$$eEdx = Vi_e(t)dt \quad \Rightarrow \quad e(V/L)(v_e dt) = Vi_e(t)dt \quad \Rightarrow \quad i_e(t) = \frac{ev_e}{L}$$

i_e flows **while the electron is drifting**, for a time $t_e = (L - l)/v_e$

Expected signals from α -particles (1)

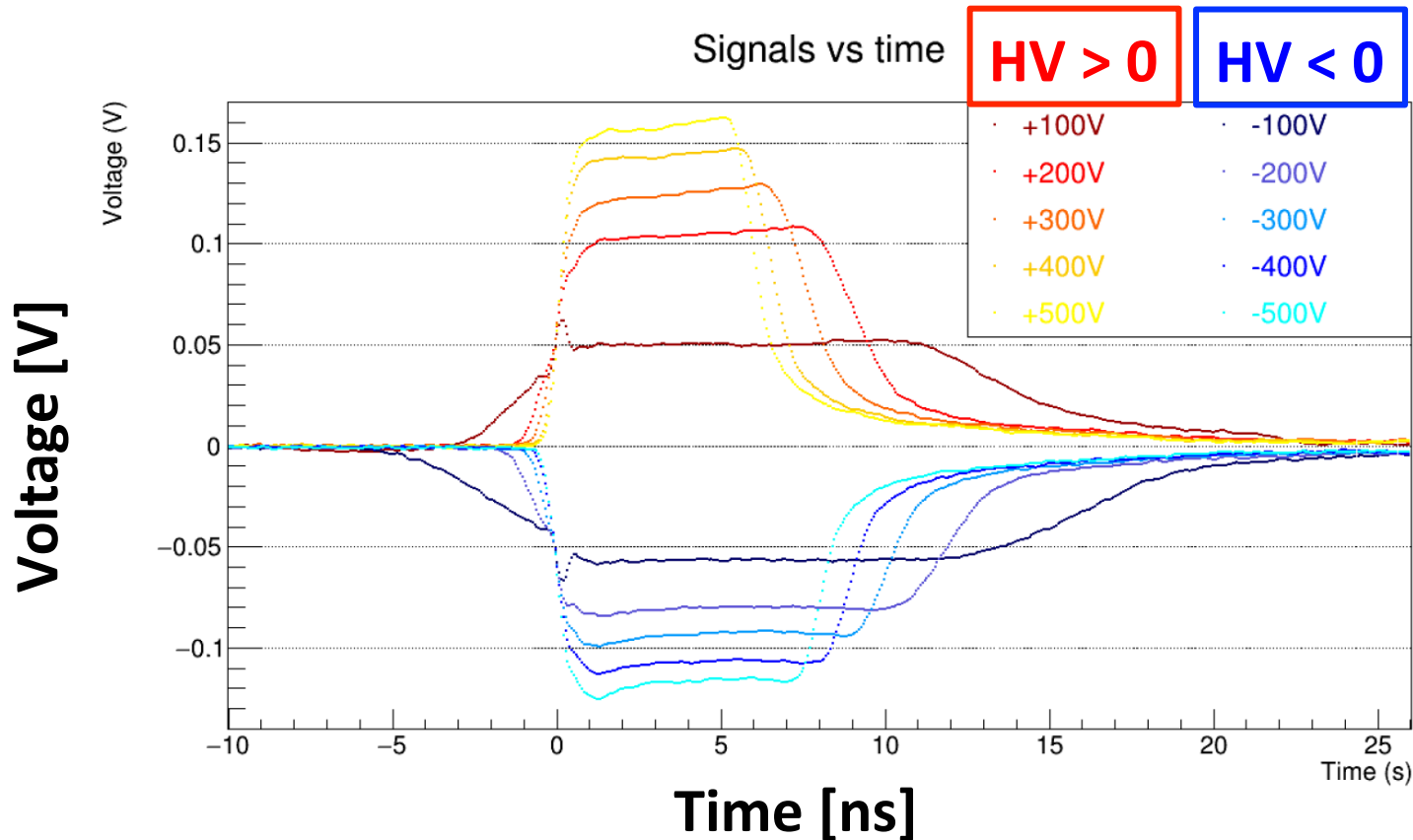
Parallel plane electrode configuration

e , h drift in uniform E -field (neglect trapping & space charge)



Reversing HV polarity and E -field:
select the charge carrier that drifts in $\approx 500 \mu\text{m}$
 \Rightarrow Measure the transport properties
of **electrons** and **holes** separately

Expected signals from α -particles (2)



Current pulse in the external circuit: $i(t) = Q(t) v(t)/d$

Voltage pulse after amplification with voltage gain G :

$$V(t) = G \cdot V_{in}(t) = G \cdot Z_{in} \cdot i(t)$$

Measurements with α -particles

Measure $V(t)$ for several HV values (positive and negative)

Average over 1000 pulses to filter background noise

Extract $i(t) = V(t)/(G \cdot Z_{in})$ where:

- G is the amplifier voltage gain
- Z_{in} is the amplifier input impedance

Qualitative interpretation:

if $i(t)$ flat, rectangular pulse \Rightarrow uniform E-field, no trapping

Quantitative results:

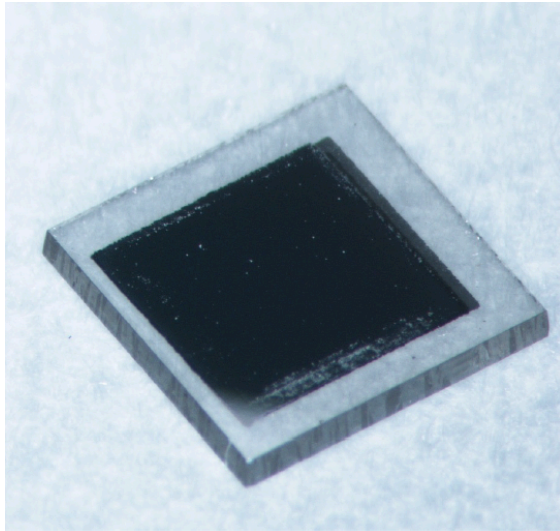
Total charge: $Q = \int_{t_i}^{t_f} i(t) dt \Rightarrow$ charge collection efficiency
 \Rightarrow energy required per e - h pair

Drift time: $\Delta t = t_f - t_i \Rightarrow$ drift velocity for e, h
 \Rightarrow mobility for e, h

EXPERIMENTAL SET-UP

DATA COLLECTION AND ANALYSIS

Our diamond sensors

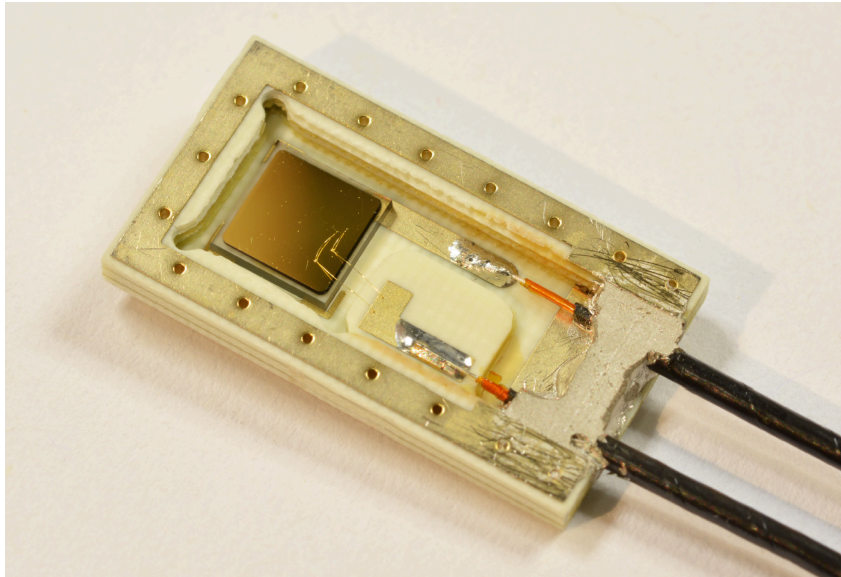


Single crystals, grown by
Chemical Vapour Deposition (s-CVD)

$(4.5 \times 4.5 \times 0.5) \text{ mm}^3$

Ti + Pt + Au electrodes

$(100 + 120 + 250) \text{ nm}$



Diamond sensor glued on a
metallized ceramic package

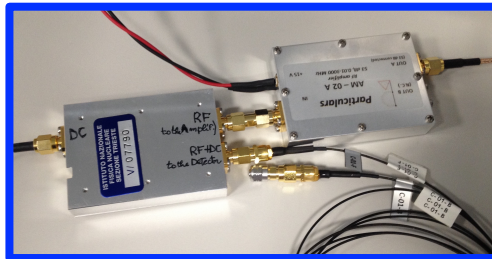
electrodes connected to coax cables

enclosed in an aluminum holder
(not shown)

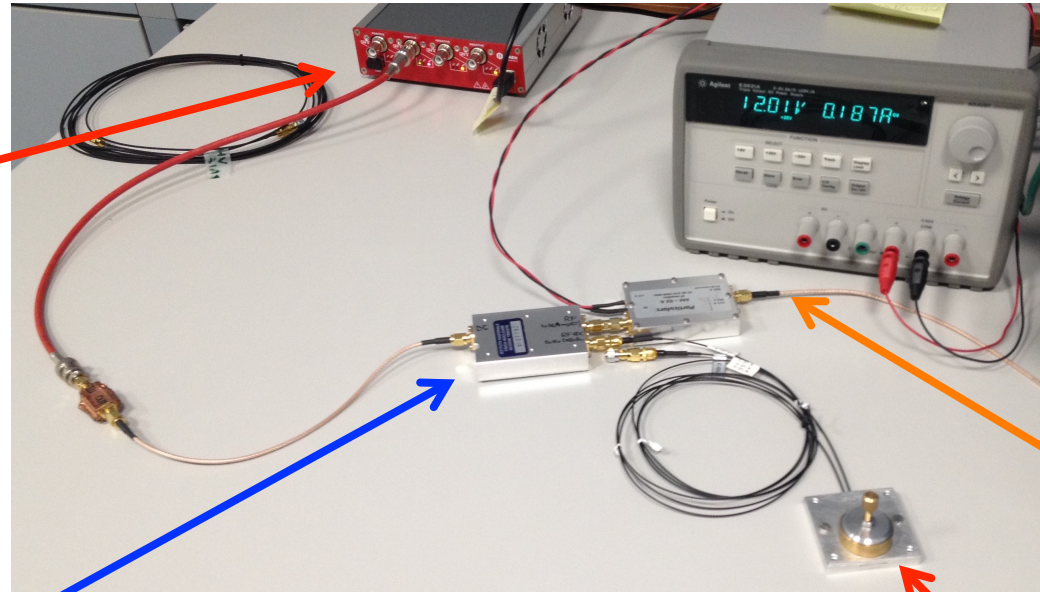
Experimental set-up



HV Power Supply
(- 800 V ÷ + 800 V)



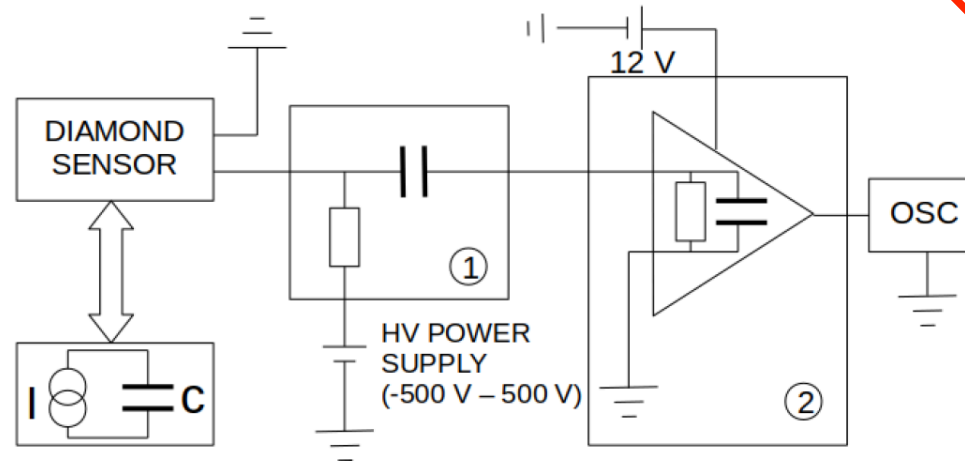
DECOUPLER (1)
AMPLIFIER (2)



Power Supply
for Amplifier
(12 V)

Signal to
Oscilloscope

Holder of
Diamond
Sensor and
Alpha Source



Data collection

Set $HV = -200\text{ V}$, take 1000 self-triggered α -events
transfer averaged data from scope to PC

Repeat, after setting $HV = -400\text{ V}, -600\text{ V}, -800\text{ V}$

Change polarity to $HV > 0$

Repeat, after setting $HV = +200, +400\text{ V}, +600\text{ V}, +800\text{ V}$

Off-line data analysis

Data analysis - 1

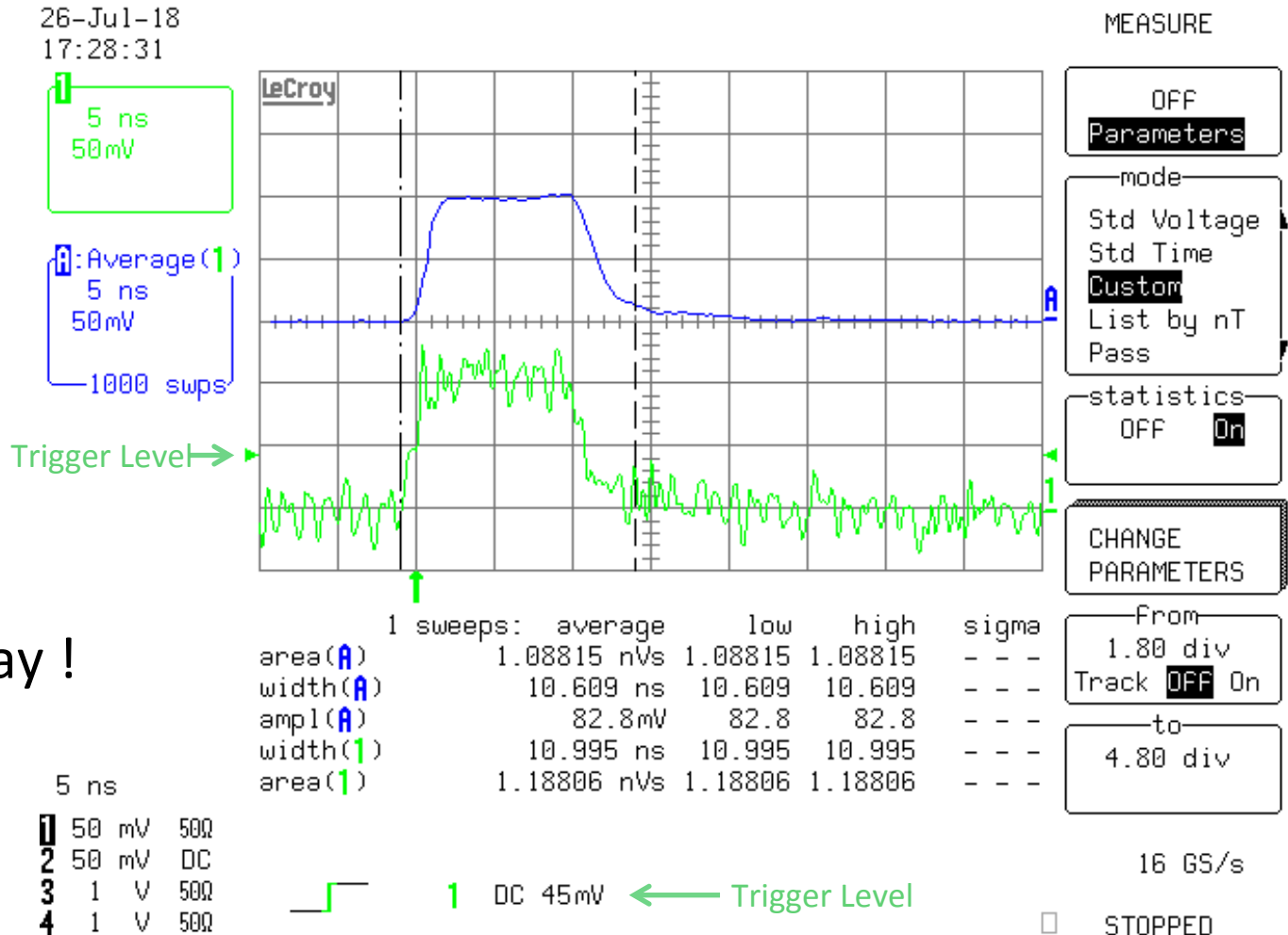
Example of scope screenshot, after collecting 1000 events: TCT_200V_Positive.BMP

Single event

Average



The average filters noise away !



Data analysis - 2

```
LECROYWP960XL,1064
Segments,1,SegmentSize,796
Segment,TrigTime,TimeSinceSegment1
#1,26-Jul-2018 17:16:06,0
Time,Ampl
-1.003e-08,-9.76525e-05
-9.969e-09,-0.000262447
-9.906e-09,-0.000433346
-9.844e-09,-0.000500485
-9.781e-09,-0.000482174
-9.719e-09,-0.000317379
-9.656e-09,-0.000170895
-9.594e-09,-0.00012817
-9.531e-09,-0.000140377
-9.469e-09,-0.000427242
-9.406e-09,-0.000695797
-9.344e-09,-0.000939938
-9.281e-09,-0.00107422
-9.219e-09,-0.00107422
-9.156e-09,-0.000933834
```

... etc

header

Data format:
Text file,
can be imported
to EXCEL

Averaged data points
Time [s], Amplitude [V]

Data analysis - 3

Preliminary step:

From output voltage back to input current, using amplifier voltage gain G and input impedance $Z_{in} = 50 \Omega$:

$$V_{in} = V_{out}/G$$

$$I_{in} = V_{in}/Z_{in}$$

Then, some quantitative results:

Total charge: $Q = \int_{t_i}^{t_f} i(t) dt$ \Rightarrow charge collection efficiency
 \Rightarrow energy required per e - h pair

Drift time: $\Delta t = t_f - t_i$ \Rightarrow drift velocity for e, h
 \Rightarrow mobility for e, h

Analysis program (Excel)

Screenshot from the analysis program (Excel spreadsheet):
can be downloaded from the link, material for this lecture

Input constants

Diamond	Thickness d	Bias Voltage	Average I	Average E	Hole Mobility μ	Energy deposited in Diamond	Ionization Energy
DC01	[cm]	[V]	[A]	[V/cm]	[cm ² /(V·s)]	[eV]	[eV]
	5.0E-02	800	8.5E-06	1.6E+04	5.4E+02	5.17E+06	1.7E+01
Input Z	Ampl. Gain	Ampl. Gain	Baseline Current	Q_{tot}			
[Ω]	[dB]	[x1]	[A]	[C]			
50.0	52	3.981E+02	-2.514E-08	4.982E-14			
Time	Output Voltage	Input Voltage	Input Current	Cumulative Charge	$Q/Q_{tot} = x/d$	v_{drift}	
[s]	[V]	[V]	[A]	[C]		[cm/s]	
-1.003E-08	-5.859E-04	-1.472E-06	-2.944E-08	0	0.000E+00		
-9.969E-09	-5.920E-04	-1.487E-06	-2.974E-08	-2.806E-19	-5.631E-06	-3.0E+04	
-9.906E-09	-5.005E-04	-1.257E-06	-2.514E-08	-2.806E-19	-5.631E-06	-2.5E+04	1.0E-0
-9.844E-09	-4.456E-04	-1.119E-06	-2.238E-08	-1.095E-19	-2.197E-06	-2.2E+04	---

Input oscilloscope data, imported from the text file

Analysis challenge

- Download excel spreadsheet and data files
- Understand the spreadsheet logics and formulae
- Import data from each text file (one per HV value) to the spreadsheet
- Compute the following quantities for at least one positive and one negative HV value:
 - Total collected charge Q
 - Averaged energy (in eV) used to generate an e-h pair
 - Drift time and drift velocity for electrons and holes
 - Mobility for electrons and holes
- Write a short report in your preferred format

A prize for the best report (teams of up to 5 participants)...!

BACK-UP SLIDES

Further reading

- **Interactions of particles with matter:**
<http://pdg.lbl.gov/2018/reviews/rpp2018-rev-passage-particles-matter.pdf>
- **Particle detectors at accelerators**
<http://pdg.lbl.gov/2018/reviews/rpp2018-rev-particle-detectors-accel.pdf>
- **Artificial diamonds**
Satoshi Koizumi, Christoph Nebel, and Milos Nesladek. Physics and applications of CVD diamond. John Wiley & Sons, 2008.
- **Diamond sensors in HEP**
<https://www.sciencedirect.com/science/article/pii/S0168900216300560>

... more on Ramo's theorem

Photodetectors

RAMO's Theorem and External Photocurrent

- An EHP is photogenerated at $x = l$. The electron and the hole drift in opposite directions with drift velocities v_h and v_e .
- The electron arrives at time $t_{electron} = (L-l)/v_e$ and the hole arrives at time $t_{hole} = l/v_h$.

